

MMT05B064T3

Preferred Devices


Thyristor Surge Protectors

High Voltage Bidirectional TSPD

These Thyristor Surge Protective devices (TSPD) prevent overvoltage damage to sensitive circuits by lightning, induction and power line crossings. They are breakover-triggered crowbar protectors. Turn-off occurs when the surge current falls below the holding current value.

Secondary protection applications for electronic telecom equipment at customer premises.

Features

- High Surge Current Capability: 50 Amps 10 x 1000 μ sec, for Controlled Temperature Environments
- The MMT05B064T3 Series is used to help equipment meet various regulatory requirements including: Bellcore 1089, ITU K.20 & K.21, IEC 950, UL 1459 & 1950 and FCC Part 68.
- Bidirectional Protection in a Single Device
- Little Change of Voltage Limit with Transient Amplitude or Rate
- Freedom from Wearout Mechanisms Present in Non-Semiconductor Devices
- Fail-Safe, Shorts When Overstressed, Preventing Continued Unprotected Operation
- Surface Mount Technology (SMT)
-  Indicates UL Recognized – File #E210057
- Pb-Free Package is Available

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Off-State Voltage – Maximum	V_{DM}	58	V
Maximum Pulse Surge Short Circuit Current Non-Repetitive Double Exponential Decay Waveform (-25°C Initial Temperature) (Notes 1 and 2)			A(pk)
2 x 10 μ sec	I_{PPS1}	± 150	
8 x 20 μ sec	I_{PPS2}	± 150	
10 x 160 μ sec	I_{PPS3}	± 100	
10 x 360 μ sec	I_{PPS4}	± 100	
10 x 560 μ sec	I_{PPS5}	± 70	
10 x 700 μ sec	I_{PPS6}	± 70	
10 x 1000 μ sec	I_{PPS7}	± 50	
Non-Repetitive Peak On-State Current 60 Hz Full Sign Wave	I_{TSM}	32	A(pk)
Maximum Non-Repetitive Rate of Change of On-State Current Exponential Waveform, < 100 A	di/dt	± 150	A/ μ s

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

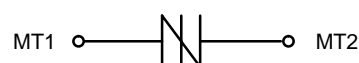
1. Allow cooling before testing second polarity.
2. Measured under pulse conditions to reduce heating.



ON Semiconductor®

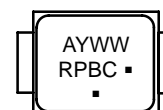
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BIDIRECTIONAL TSPD () 50 AMP SURGE, 64 VOLTS



SMB
(No Polarity)
(Essentially JEDEC DO-214AA)
CASE 403C

MARKING DIAGRAM



A = Assembly Location
Y = Year
WW = Work Week
RPBC = Device Code
▪ = Pb-Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
MMT05B064T3	SMB	2500 Tape & Reel
MMT05B064T3G	SMB (Pb-Free)	2500 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Operating Temperature Range Blocking or Conducting State	T_{J1}	-40 to +125	°C
Overload Junction Temperature – Maximum Conducting State Only	T_{J2}	+175	°C
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	T_L	260	°C

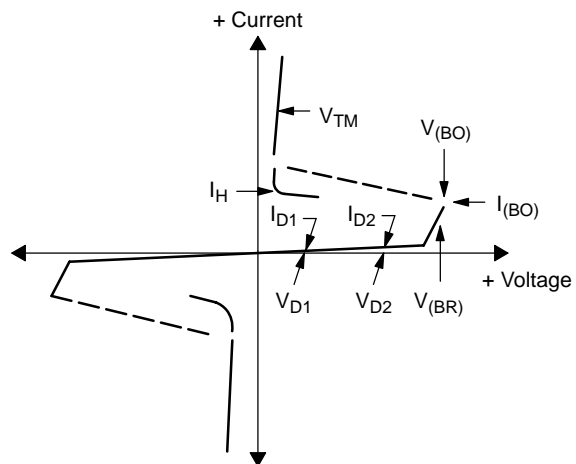
ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise noted) Devices are bidirectional. All electrical parameters apply to forward and reverse polarities.

Characteristics	Symbol	Min	Typ	Max	Unit
Breakover Voltage (Both polarities) ($dv/dt = 100 \text{ V}/\mu\text{s}$, $I_{SC} = 1.0 \text{ A}$, $V_{dc} = 1000 \text{ V}$) (+65°C)	$V_{(BO)}$	-	-	77 80	V
Breakover Voltage (Both polarities) ($f = 60 \text{ Hz}$, $I_{SC} = 1.0 \text{ A(rms)}$, $V_{OC} = 1000 \text{ V(rms)}$, $R_f = 1.0 \text{ k}\Omega$, $t = 0.5 \text{ cycle}$) (Note 3) (+65°C)	$V_{(BO)}$	-	-	77 80	V
Breakover Voltage Temperature Coefficient	$dV_{(BO)}/dT_J$	-	0.054	-	V/°C
Breakdown Voltage ($I_{(BR)} = 1.0 \text{ mA}$) Both polarities	$V_{(BR)}$	58	-	-	V
Off State Current ($V_{D1} = 50 \text{ V}$) Both polarities ($V_{D2} = V_{DM}$) Both polarities	I_{D1} I_{D2}	-	-	2.0 5.0	μA
On-State Voltage ($I_T = 1.0 \text{ A}$) ($PW \leq 300 \mu\text{s}$, Duty Cycle $\leq 2\%$) (Note 3)	V_T	-	-	3.0	V
Breakover Current ($f = 60 \text{ Hz}$, $V_{DM} = 1000 \text{ V(rms)}$, $R_S = 1.0 \text{ k}\Omega$) Both polarities	I_{BO}	-	91	-	mA
Holding Current (Both polarities) (Note 3) $V_S = 500 \text{ V}$; I_T (Initiating Current) = $\pm 1.0 \text{ A}$ (+65°C)	I_H	150 130	- -	- -	mA
Critical Rate of Rise of Off-State Voltage (Linear waveform, $V_D = \text{Rated } V_{BR}$, $T_J = 25^\circ\text{C}$)	dv/dt	2000	-	-	V/ μs
Capacitance ($f = 1.0 \text{ MHz}$, 50 Vdc , 1.0 V rms Signal) ($f = 1.0 \text{ MHz}$, 2.0 Vdc , 1.0 V rms Signal)	C_O	-	42 80	- -	pF

3. Measured under pulse conditions to reduce heating.

**Voltage Current Characteristic of TSPD
(Bidirectional Device)**

Symbol	Parameter
I_{D1} , I_{D2}	Off State Leakage Current
V_{D1} , V_{D2}	Off State Blocking Voltage
V_{BR}	Breakdown Voltage
V_{BO}	Breakover Voltage
I_{BO}	Breakover Current
I_H	Holding Current
V_{TM}	On State Voltage



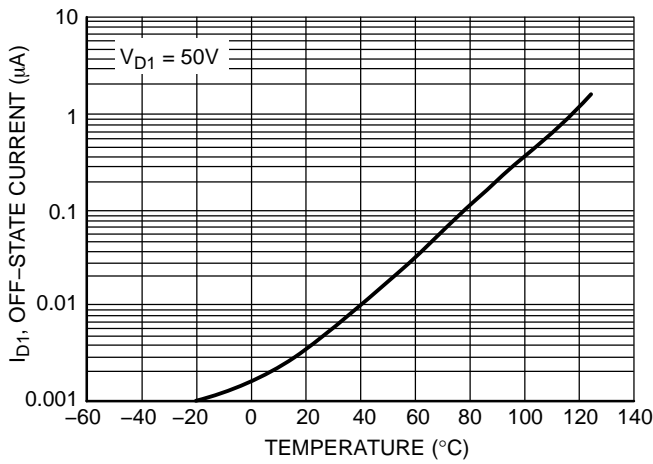


Figure 1. Typical Off-State Current versus Temperature

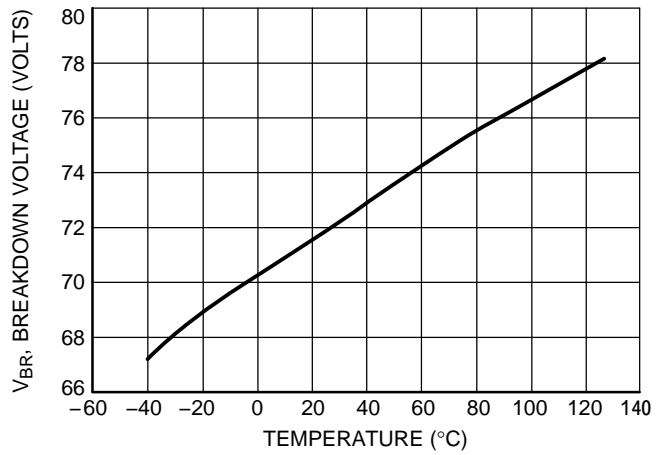


Figure 2. Typical Breakdown Voltage versus Temperature

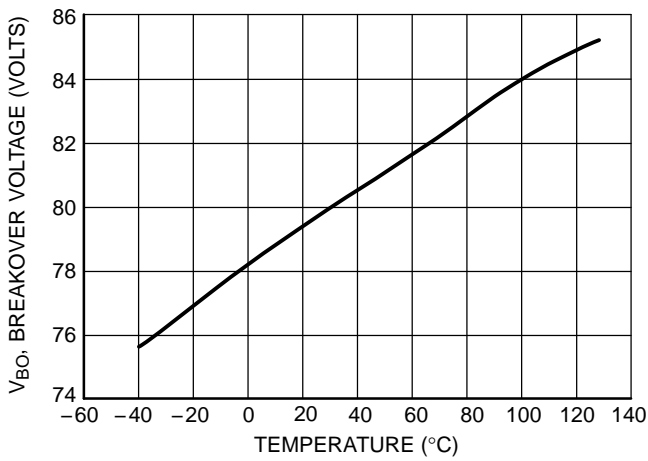


Figure 3. Maximum Breakover Voltage versus Temperature

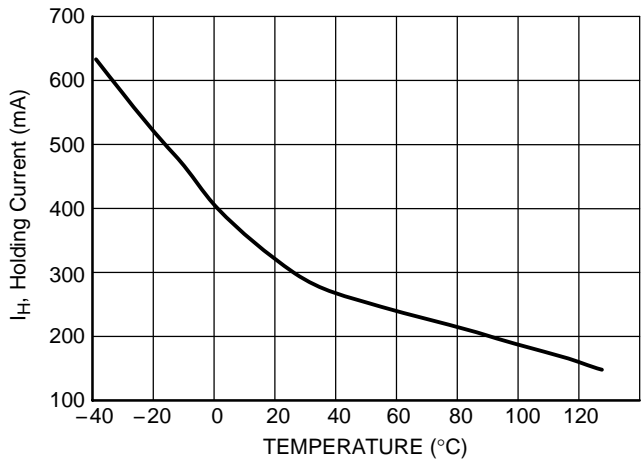


Figure 4. Typical Holding Current versus Temperature

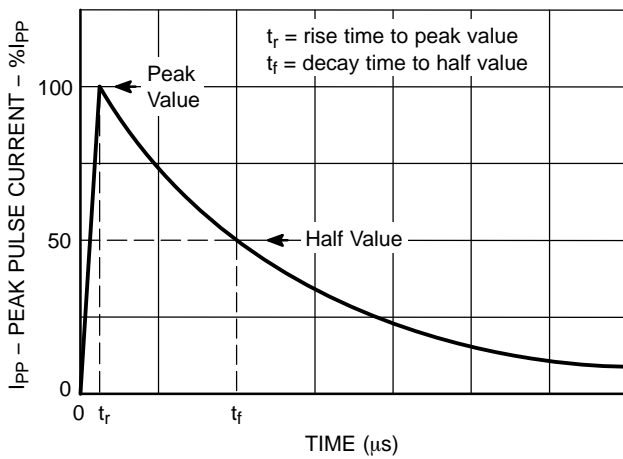


Figure 5. Exponential Decay Pulse Waveform

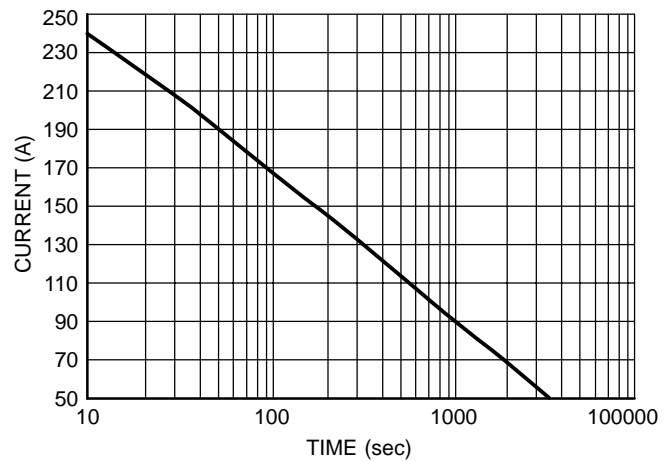
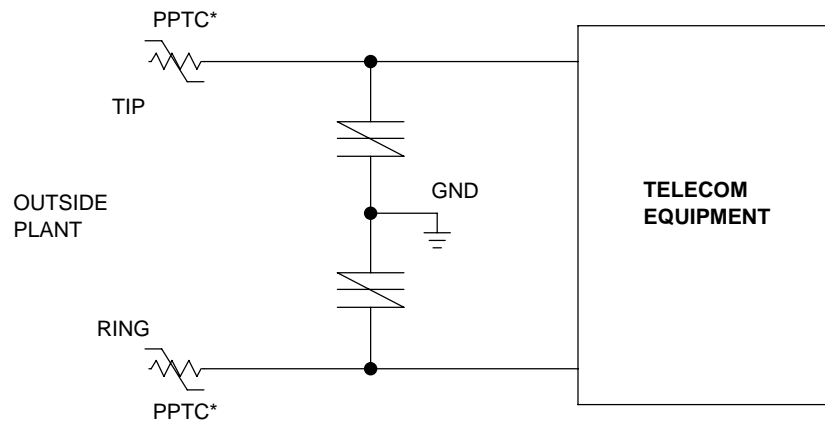
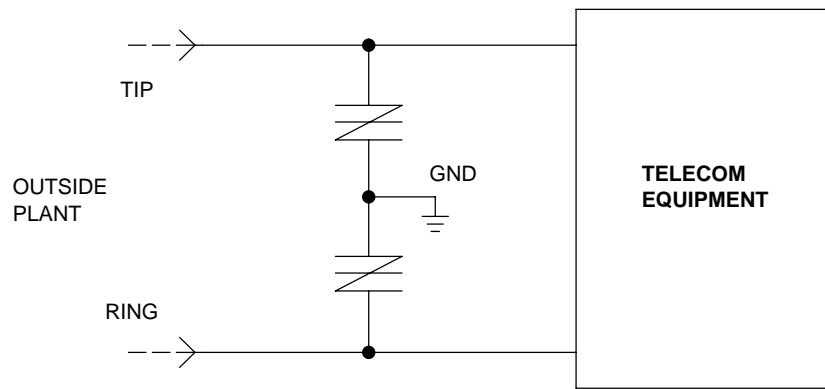
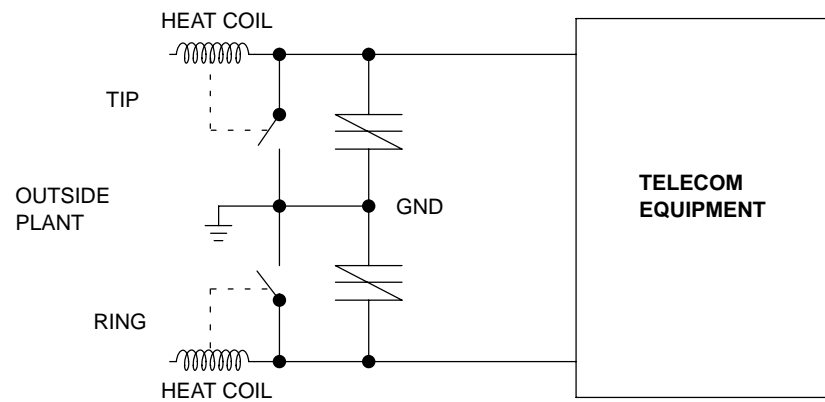


Figure 6. Peak Surge On-State Current versus Surge Current Duration, Sinusoidal Waveform

MMT05B064T3



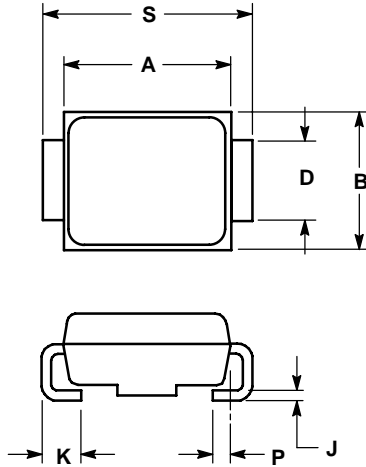
*Polymeric PTC (positive temperature coefficient) overcurrent protection device



MMT05B064T3

PACKAGE DIMENSIONS

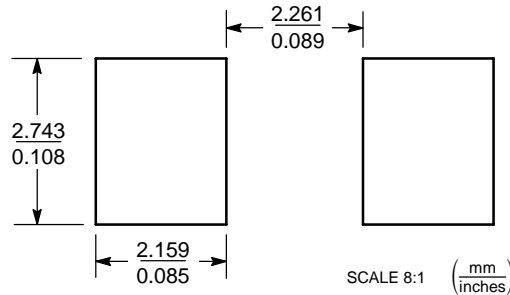
SMB CASE 403C-01 ISSUE A




- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.160	0.180	4.06	4.57
B	0.130	0.150	3.30	3.81
C	0.075	0.095	1.90	2.41
D	0.077	0.083	1.96	2.11
H	0.0020	0.0060	0.051	0.152
J	0.006	0.012	0.15	0.30
K	0.030	0.050	0.76	1.27
P	0.020 REF		0.51 REF	
S	0.205	0.220	5.21	5.59

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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